VCXO/VCSO VG5032EDN

Product name VG5032EDN 108.000000MHz CJHHBA
Product code / Ordering code X1G0049110025xx
Please refer to the 8.Packing information about xx (last 2 digits)

Output waveform LV-PECL
Pb free / Complies with EU RoHS directive
Reference weight Typ.64 mg

1.Absolute maximum ratings

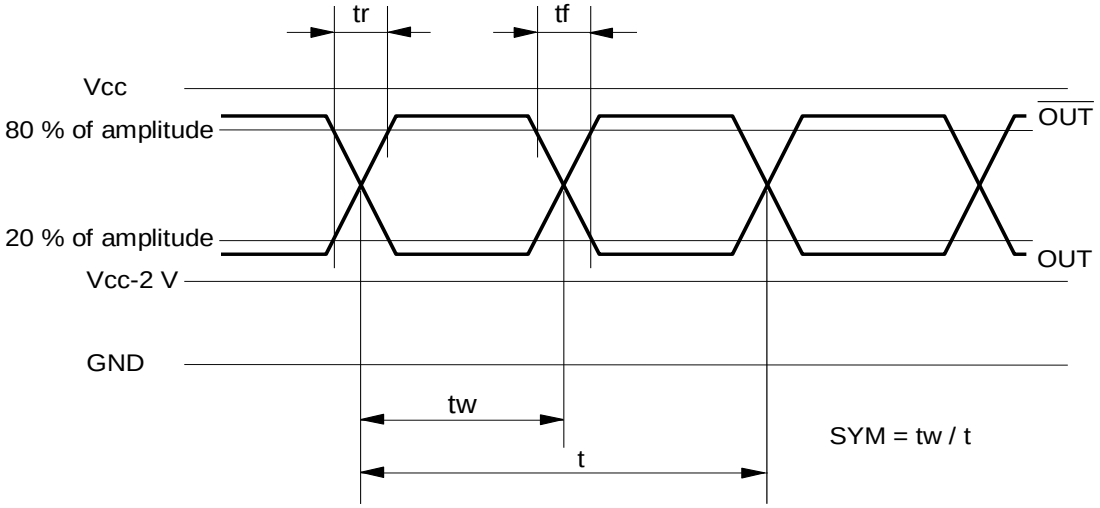
Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions / Remarks
Maximum supply voltage	Vcc-GND	-0.5	-	+5	V	-
Storage temperature	T_stg	-55	-	+125	ºC	-
Input voltage	Vin	-0.5	-	Vcc+0.5	V	Vc pin

2.Specifications(characteristics)

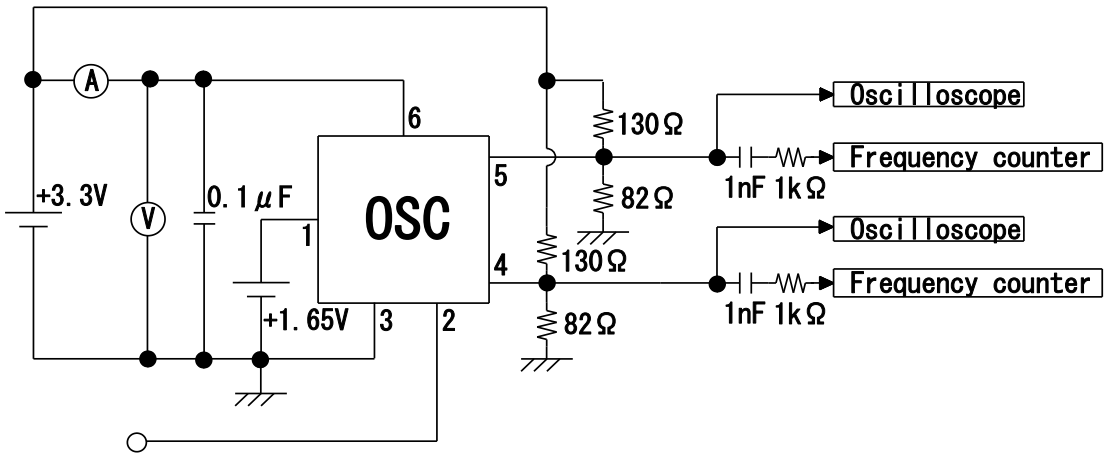
Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions / Remarks
Output frequency	f0		108.0000		MHz	
Supply voltage	Vcc	3.135	3.3	3.465	V	-
Control voltage	Vc	0	1.65	3.3	V	-
Operating temperature	T_use	-40	-	+105	ºC	-
Frequency tolerance	f_tol	-50	-	+50	$x10^{-6}$	includes 20 years aging
Current consumption	Icc	-	-	60	mA	L_ECL =50Ω
Disable current	I_dis	-	-	-	mA	-
Frequency control range	f_cont	+/-100	-	-	$x10^{-6}$	-
Absolute pull range	APR	+/-50	-	-	$x10^{-6}$	Vc=1.65V+/-1.65V
Modulation characteristics	BW	10	-	-	kHz	+/-3 dB
Input resistance	Rin	100	-	-	kΩ	DC Level
Frequency change polarity	-					Positive polarity
Symmetry	SYM	45	-	55	%	Vcc-1.3V, Vc=Vcc/2
Output voltage	VOH	Vcc-1.1	-	-	V	-
	VOL	-	-	Vcc-1.5	V	-
Output load condition	L_ECL	-	50	-	Ω	Outputs terminated to Vcc-2.0V
Input voltage	VIH	70%Vcc	-	-	V	OE pin
	VIL	-	-	30%Vcc	V	OE pin
Rise time	tr	-	-	0.5	ns	20 % to 80 % of amplitude
Fall time	tf	-	-	0.5	ns	20 % to 80 % of amplitude
Start-up time	t_str	-	-	10	ms	t=0 at 90 %Vcc
Phase noise	F_{CN}	-	-65	-	dBc/Hz	Offset 10Hz
		-	-97	-	dBc/Hz	Offset 100Hz
		-	-124	-	dBc/Hz	Offset 1kHz
		-	-138	-	dBc/Hz	Offset 10kHz
		-	-147	-	dBc/Hz	Offset 100kHz
Phase jitter	t_{PJ}	-	0.15	-	ps	Offset Frequency: 12kHz to 20MHz
Frequency aging	f_aging	-	-	-	$x10^{-6}$	Included in frequency tolerance

3.Timing chart

Output wave form



4.Test circuit



[Pin connection]

1. Vc
2. OE
3. GND
4. OUT1 (Positive)
5. OUT2 (Negative)
6. Vcc

3) Condition

(1) Oscilloscope

- Bandwidth should be 5 times higher than DUT's output frequency.
- Probe ground should be placed closely from test point and lead length should be as short as possible.

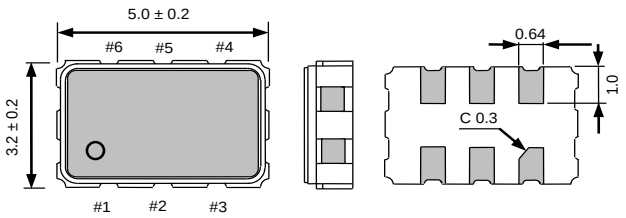
(2) By-pass capacitor (approx. 0.01μF to 0.1 μF) should be placed closely between Vcc and GND.

(3) Use the current meter whose internal impedance value is small.

(4) Power supply

- Start up time(0 V→90 %Vcc)of power source should be more than 150μs.
- Impedance of power supply should be as low as possible.

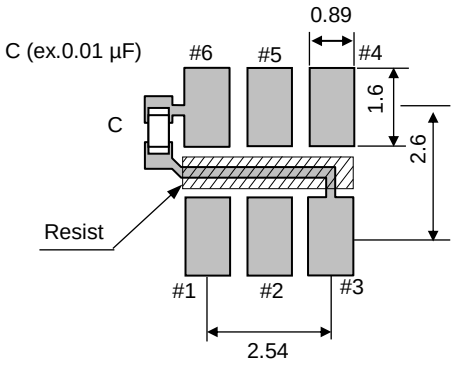
5.External dimensions (Unit: mm)



Pin map

Pin	Connection
1	Vc
2	OE
3	GND
4	OUT1(positive)
5	OUT2(Negative)
6	Vcc

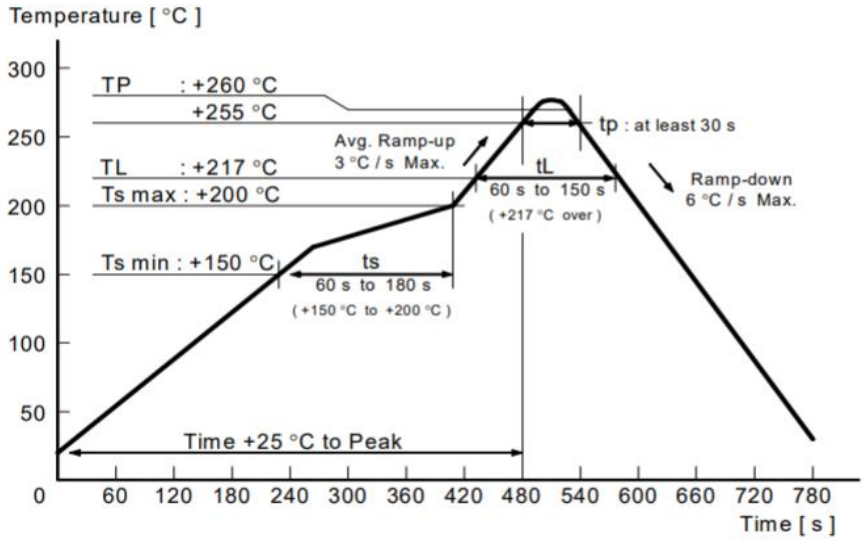
6.Footprint(Recommended) (Unit: mm)



To maintain stable operation, provide a 0.01uF to 0.1uF by-pass capacitor at a location as near as possible to the power source terminal of the crystal product (between Vcc - GND).

7.Reflow profile

Reflow condition (Follow of JEDEC STD-020D.01)



8.Packing information

[1]Product number last 2 digits code(xx) description

The recommended code is "00"

X1G0049110025xx

Code	Condition
00	1000pcs / Reel
01	Any Q'ty vinyl bag(Tape cut)
11	Any Q'ty / Reel

[2] Taping specification

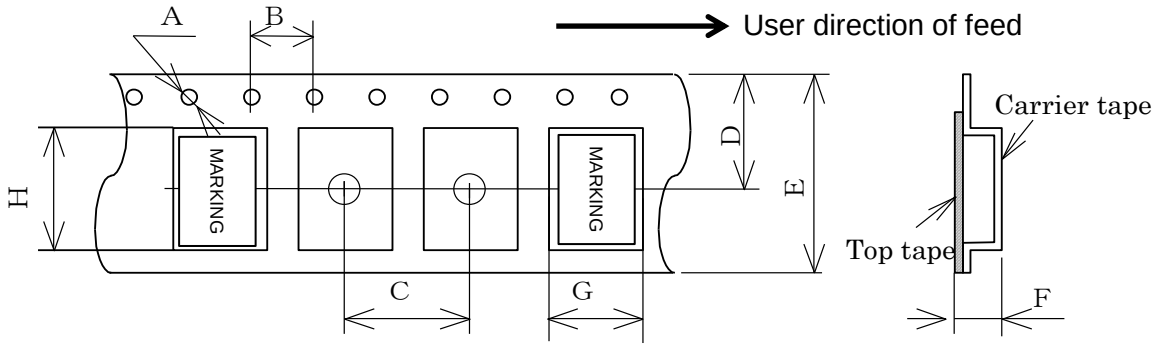
Subject to EIA-481 & IEC-60286

(1) Tape dimensions

Material of the Carrier Tape : PS

Material of the Top Tape : PET

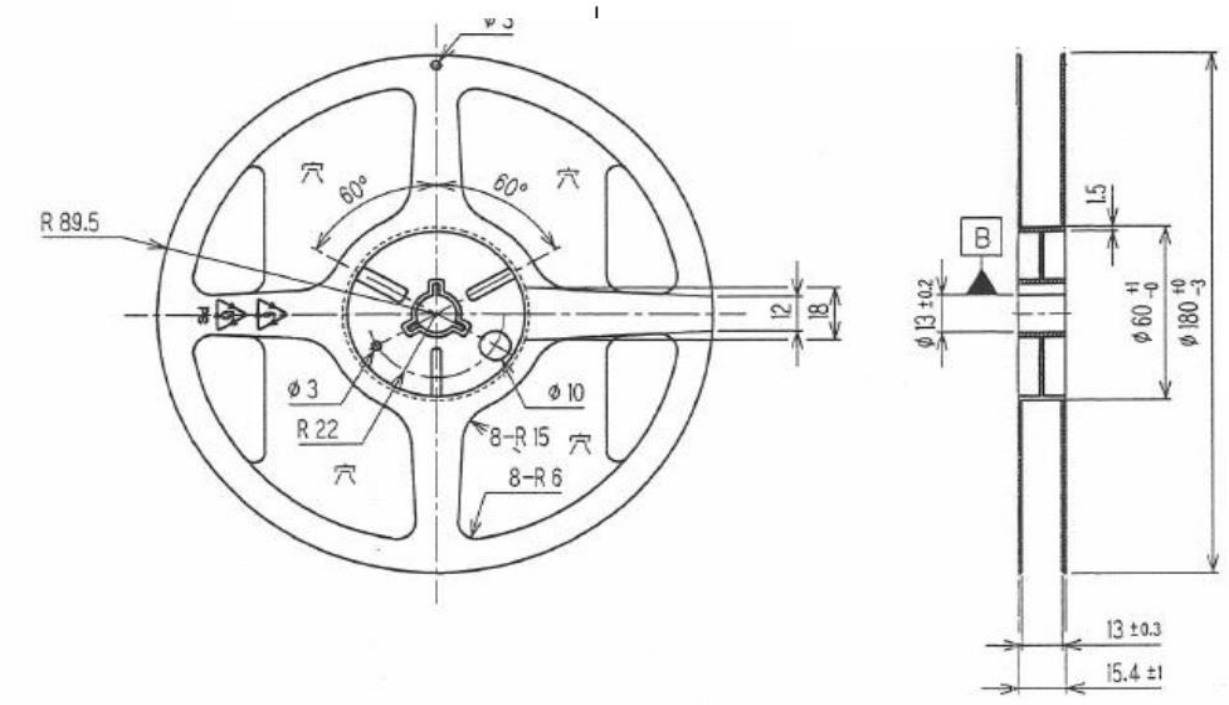
Unit: mm



Symbol	A	B	C	D	E	F	G	H
Value	Φ1.5	4.0	8.0	7.25	12.0	1.7	3.5	5.4

(2) Reel dimensions

Material of the Reel : PS



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